TOSHIBA Transistor Silicon NPN Triple Diffused Type

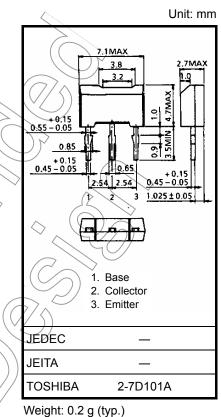
# 2SC6040

High-Speed and High-Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

- High-speed switching:  $t_f = 0.2 \ \mu s \ (max) \ (I_C = 0.3 \ A)$
- High breakdown voltage:  $V_{CES} = 800 \text{ V}, V_{CEO} = 410 \text{ V}$

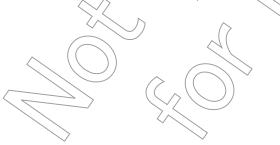
#### Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	$\langle \rangle$
Collector-base voltage		V <sub>CBO</sub>	800	$(\sqrt{2})$	
Collector-emitter voltage		V <sub>CES</sub>	800	×	
Collector-emitter voltage		V <sub>CEO</sub>	410	×	
Emitter-base voltage		V <sub>EBO</sub>	8	> v	
Collector current	DC	Ι <sub>C</sub>	1.0	А	(
	Pulse	I <sub>CP</sub>	2.0	A	
Base current		I <sub>B</sub>	0.5	/ A	$\backslash$
Collector power dissipation	Ta = 25°C	PC	1.0	×	$\checkmark$
Junction temperature			150	°C	$\sim$
Storage temperature range			-55 to 150	°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

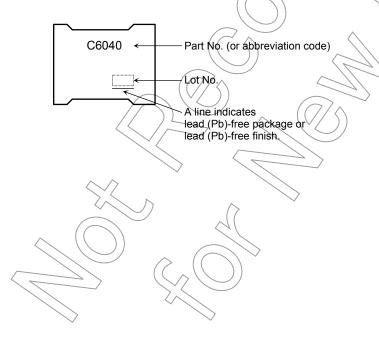
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



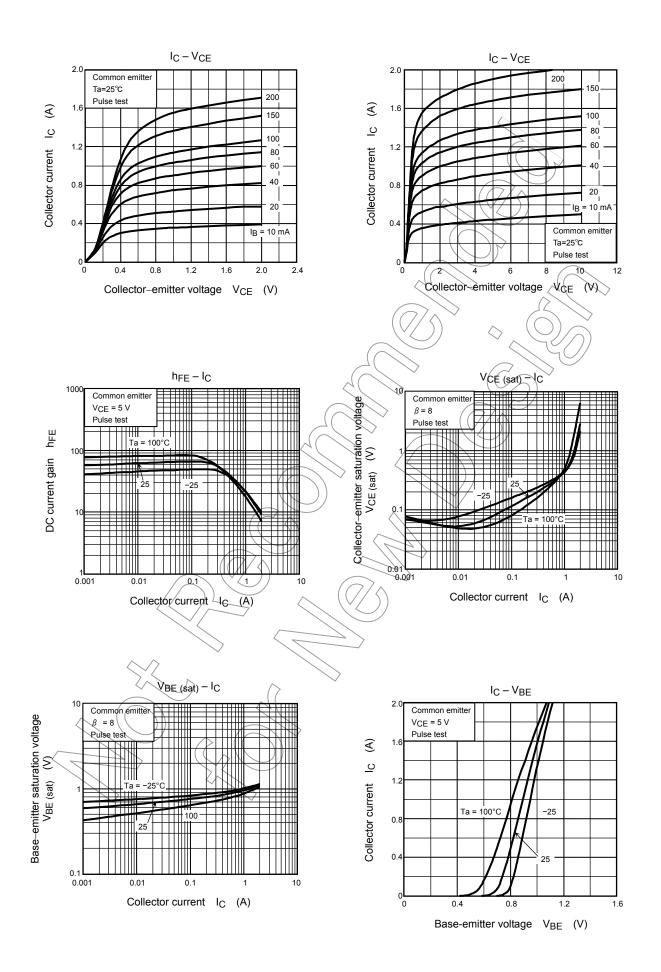
Electrical Characteristics (Ta = 25°C)

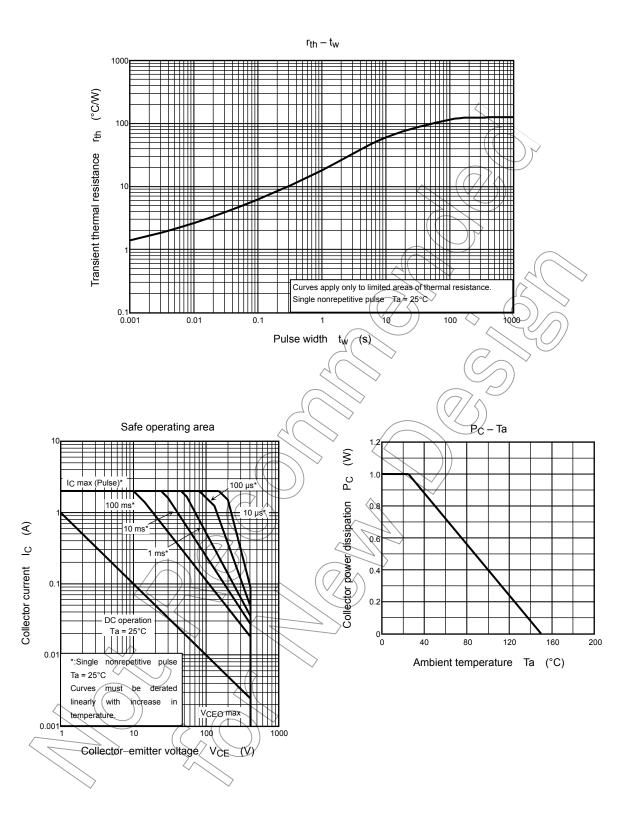
Char	acteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I <sub>CBO</sub>	V <sub>CB</sub> = 800 V, I <sub>E</sub> = 0	_	_	100	μA
Emitter cut-off cu	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 8 V, I <sub>C</sub> = 0	_	_	100	μA
Collector-base breakdown voltage		V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>B</sub> = 0	800	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	410	1	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	50			
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.1 A	_	120		
		h <sub>FE (3)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.2 A	50	_	_	
Collector emitter saturation voltage V		V <sub>CE (sat)</sub>	I <sub>C</sub> = 0.8 A, I <sub>B</sub> = 0.1 A	_	_	1.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 0.8 A, I <sub>B</sub> = 0.1 A	_	_	1.3	V
Switching time	Rise time	tr	20 μs ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓	_		0,5	
	Storage time	t <sub>stg</sub>				4.0	μs
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = 0.1 A, -I <sub>B2</sub> = 50 mA DUTX CYCLE ≤ 1%	2)	_	0.2	

### Marking



## **TOSHIBA**





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